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(54) **ORGANIC LIGHT-EMITTING DISPLAY APPARATUS AND METHOD OF MANUFACTURING THE SAME**

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(57) **ABSTRACT**

(51) **Int. Cl.**
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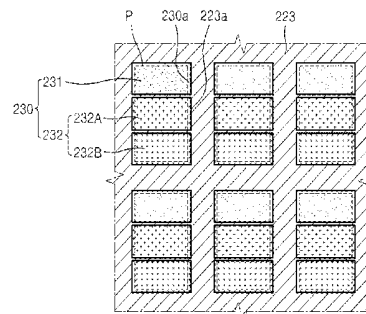
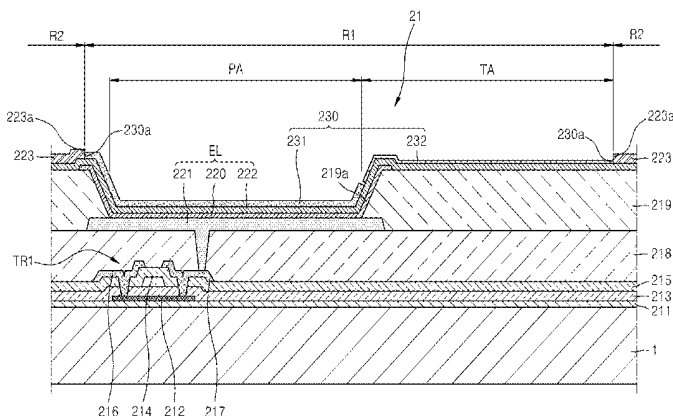
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An organic light-emitting display apparatus including: a substrate; a plurality of pixels that are formed on the substrate and each have a light emission area from which visible rays are emitted and a transmission area through which external light is transmitted; a pixel circuit portion disposed in each light emission area of the plurality of pixels; a first electrode that is disposed in each light emission area and is electrically connected to the pixel circuit portion; an intermediate layer that is formed on the first electrode and includes an organic emissive layer; a second electrode formed on the intermediate layer; and a capping layer that is disposed on the second electrode and includes a first capping layer corresponding to the light emission area and a second capping layer corresponding to the transmission area. Accordingly, electrical characteristics and image quality of the organic light-emitting display apparatus may be improved.

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7 Claims, 7 Drawing Sheets



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 CPC H01L 51/54; H01L 51/56; H01L 27/15; H01L 27/32–27/3293; H01L 27/3202–27/3204; H01L 27/3241–27/3297; H01L 27/3225–27/3234; H01L 27/3246; H01L 27/3248; H01L 27/3251; H01L 27/3258; H01L 27/326; H01L 33/08; H01L 2227/322; H01L 2227/326; H01L 51/5253; H01L 51/5256; H01L 27/3276; H01L 33/36; H01L 51/52
 USPC 257/59, 72, 40, 98, 99, E51.027, 257/E51.026, E51.018, E21.158, 28, 71, 257/E51.022, 88; 438/29, 34, 82, 99; 345/76, 80; 313/512
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See application file for complete search history.

FIG. 1

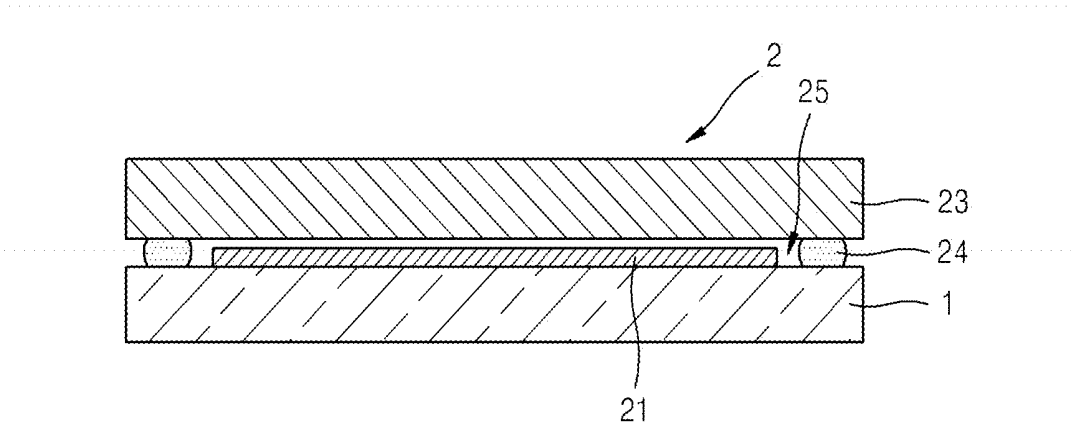


FIG. 2

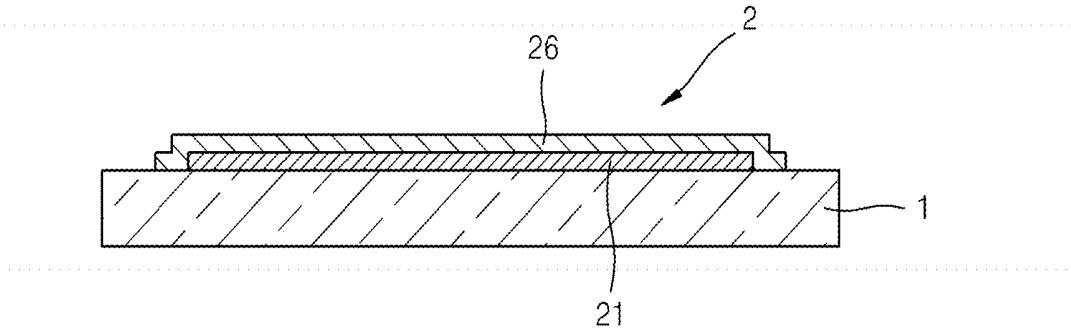


FIG. 3

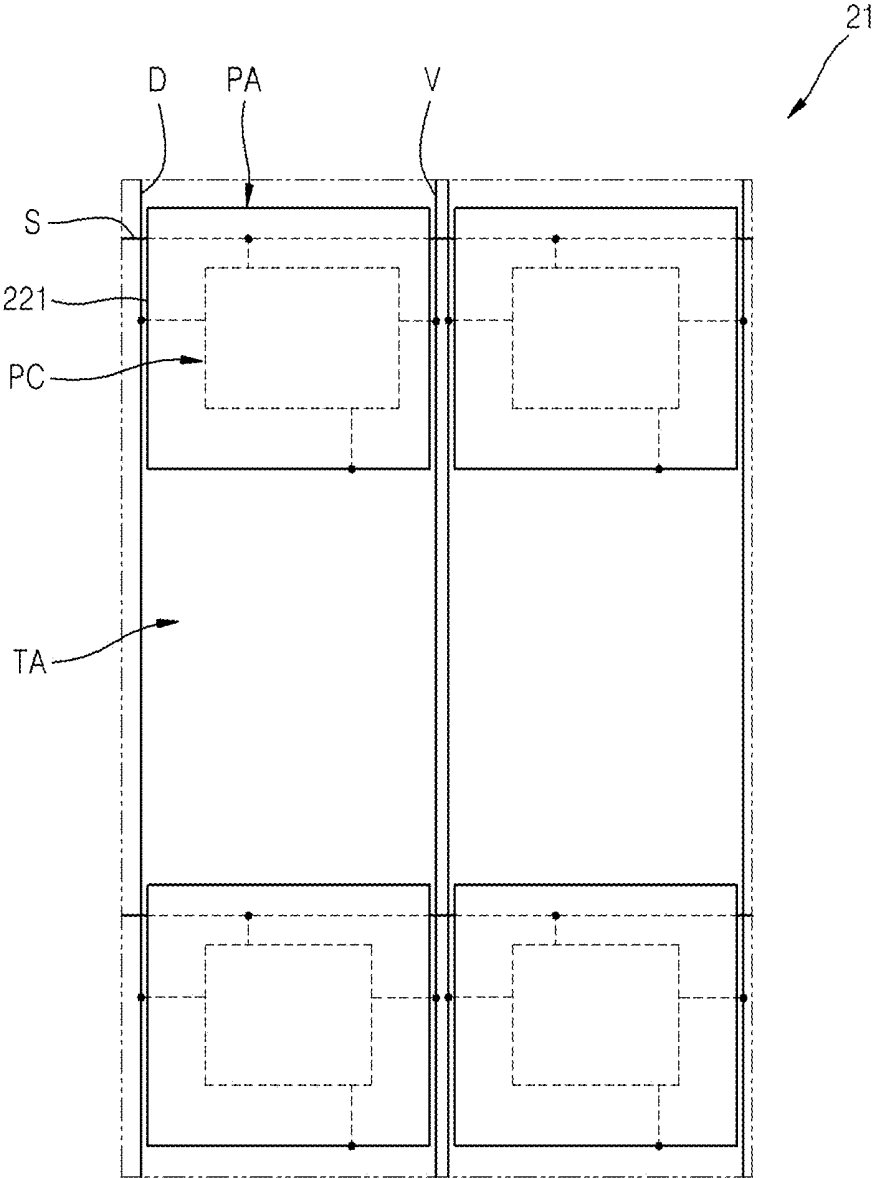


FIG. 5

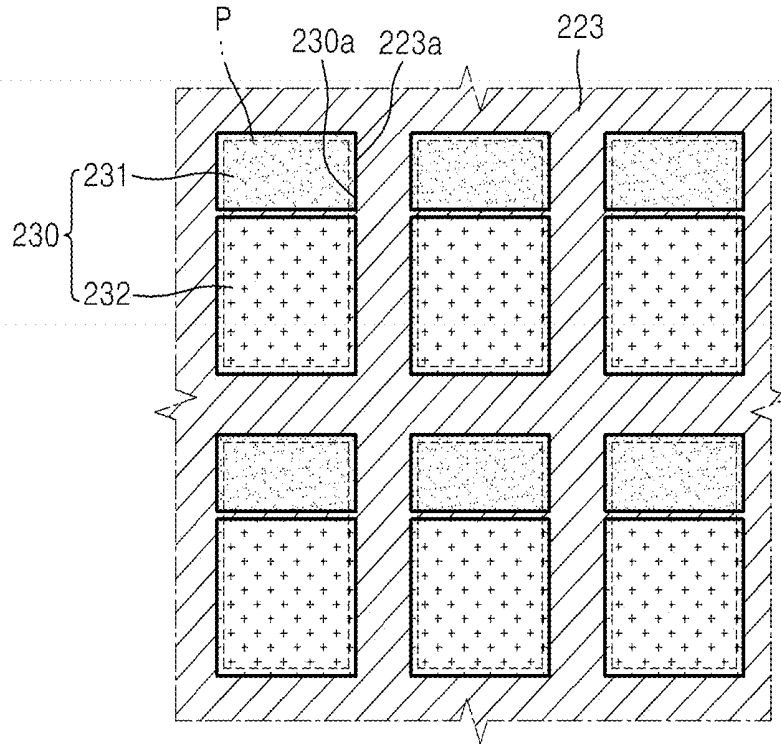


FIG. 6

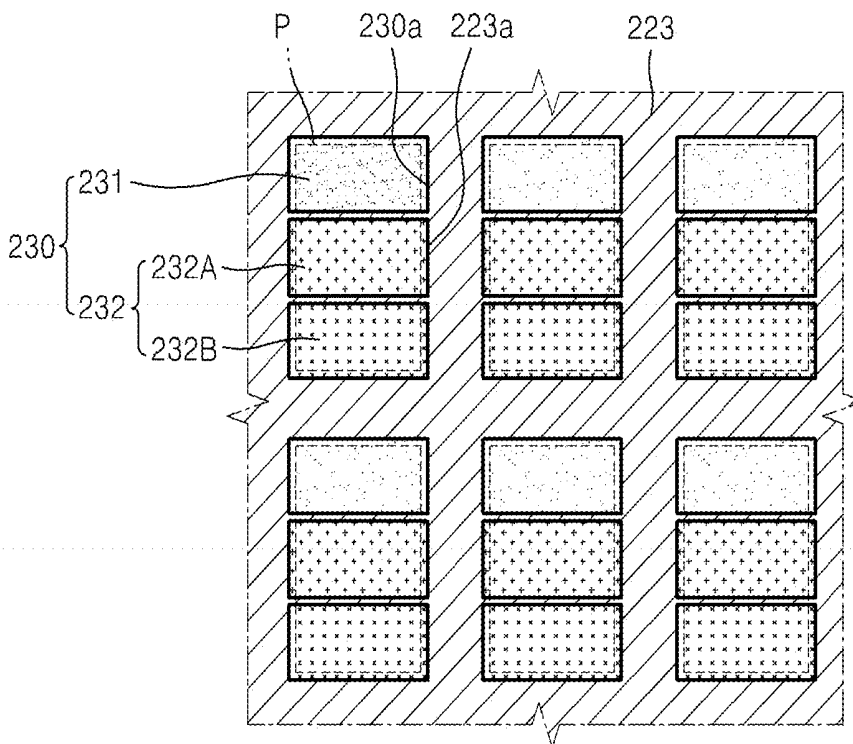


FIG. 7

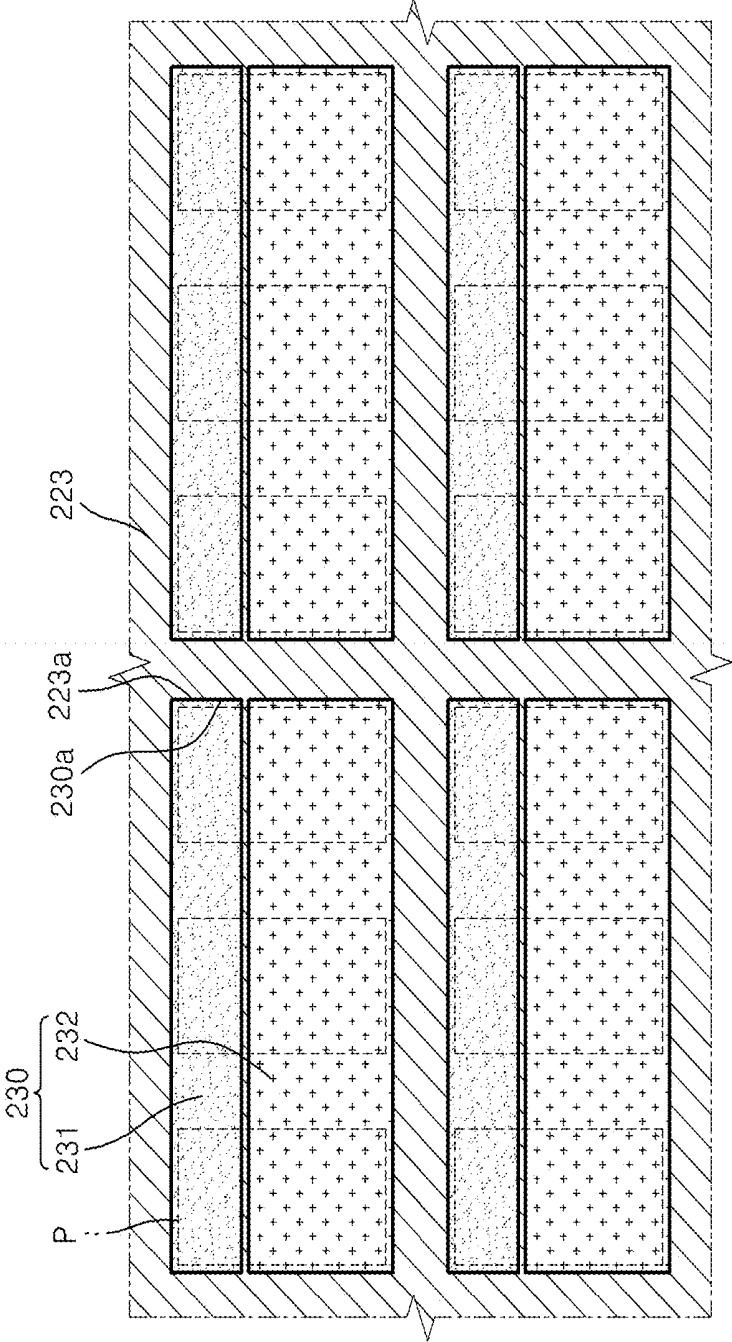


FIG. 8

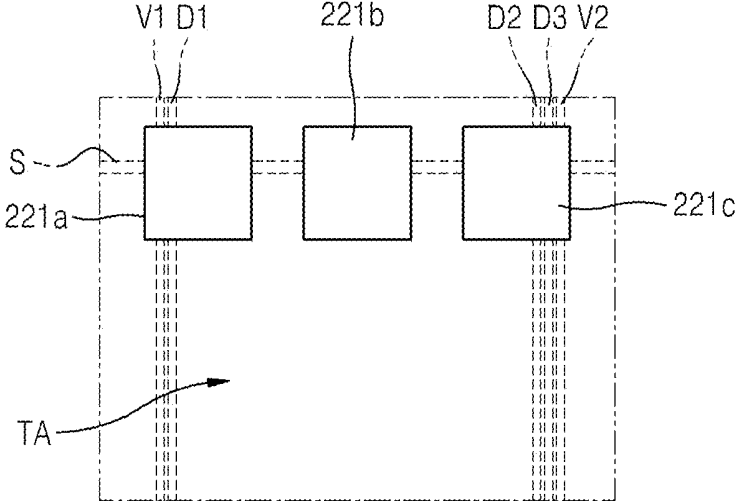
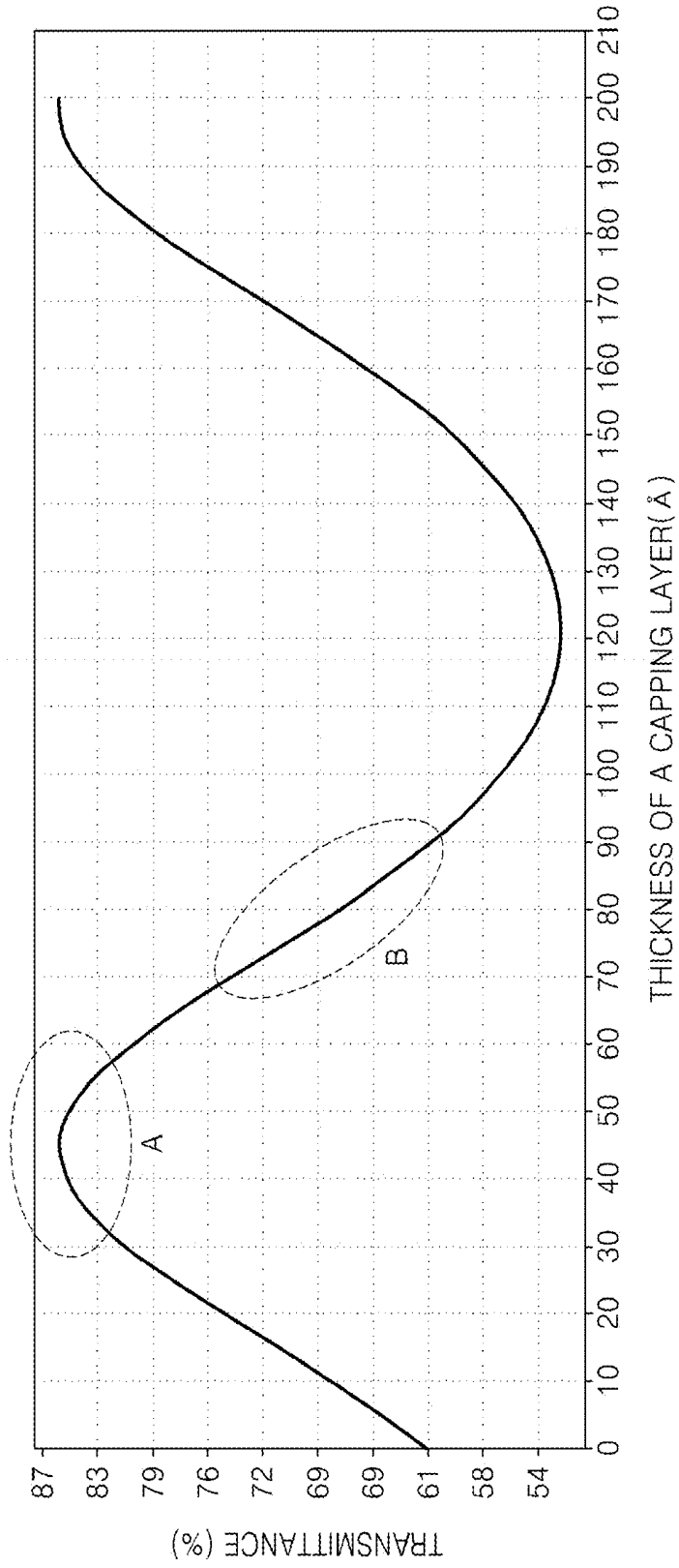


FIG. 9



**ORGANIC LIGHT-EMITTING DISPLAY
APPARATUS AND METHOD OF
MANUFACTURING THE SAME**

CROSS-REFERENCE TO RELATED PATENT
APPLICATION

This application is a divisional application of U.S. patent application Ser. No. 13/443,820, filed on Apr. 10, 2012, which claims priority to and the benefit of Korean Patent Application No. 10-2011-0141719, filed on Dec. 23, 2011, in the Korean Intellectual Property Office, the disclosures of which are incorporated herein in their entirety by reference.

BACKGROUND

1. Field

The following description relates to an organic light-emitting display apparatus and a method of manufacturing the same.

2. Description of the Related Art

Flat panel display apparatuses are thin and portable display apparatuses. Among the flat panel display apparatuses, organic light-emitting display apparatuses are self-emissive display apparatuses which have wide viewing angles, excellent contrast, and high response speeds. Thus, the organic light-emitting display apparatuses are being recognized (noticed) as next-generation display apparatuses.

An organic light-emitting display apparatus includes an intermediate layer, a first electrode, and a second electrode. The intermediate layer includes an organic emissive layer, and when a voltage is applied to the first and second electrodes, the organic emissive layer produces visible rays.

Here, due to a sealing member disposed on the second electrode or other impurities, the second electrode may be polluted or damaged.

Thus, it is difficult to improve image quality and electrical characteristics of the organic light-emitting display apparatus.

SUMMARY

Aspects of embodiments of the present invention are directed toward an organic light-emitting display apparatus having improved electrical characteristics and/or image quality, and a method of manufacturing the organic light-emitting display apparatus.

According to an embodiment of the present invention, there is provided an organic light-emitting display apparatus including: a substrate; a plurality of pixels that are formed on the substrate and each have a light emission area from which visible rays are emitted and a transmission area through which external light is transmitted; a pixel circuit portion disposed in each light emission area of the plurality of pixels; a first electrode that is disposed in each light emission area and is electrically connected to the pixel circuit portion; an intermediate layer that is formed on the first electrode and includes an organic emissive layer; a second electrode formed on the intermediate layer; and a capping layer that is disposed on the second electrode and includes a first capping layer corresponding to the light emission area and a second capping layer corresponding to the transmission area.

The capping layer may be light-transmissive.

The first capping layer and the second capping layer may have different thicknesses.

The second capping layer may be thinner than the first capping layer.

5 The second capping layer may include a plurality of sub-capping layers.

The first capping layer and the second capping layer may be separated from each other in at least a first direction and a second direction perpendicular to the first direction (or in at least one area).

10 The first capping layer and the second capping layer may include the same material.

The first capping layer and the second capping layer may include different materials.

15 The capping layer may comprise 8-quinolinolato lithium (Liq), N,N-diphenyl-N,N-bis(9-phenyl-9H-carbazol-3-yl)biphenyl-4,4'-diamine, N(diphenyl-4-yl)9,9-dimethyl-N-(4(9-phenyl-9H-carbazol-3-yl)phenyl)-9H-fluorene-2-amine, or 2-(4-(9,10-di(naphthalene-2-yl)anthracene-2-yl)phenyl)-1-phenyl-1H-benzo-[D]imidazole.

The second electrode may be light-transmissive.

The capping layer may be formed on the second electrode in a first area and has a first edge, the organic light-emitting display apparatus may further include a third electrode that is formed on the second electrode in a second area other than the first area (or in an entire top surface area of the second electrode except the first area) and has a second edge, and a lateral surface of the first edge of the capping layer and a lateral surface of the second edge of the third electrode contact each other.

20 The third electrode may be thicker than the second electrode.

An adhesive force between the third electrode and the capping layer may be weaker than an adhesive force between the third electrode and the second electrode.

25 The third electrode may comprise magnesium (Mg).

All edges of the capping layer and an edge of the third electrode may contact each other.

30 According to another embodiment of the present invention, there is provided a method of manufacturing an organic light-emitting display apparatus including a plurality of pixels each including a light emission area from which visible rays are emitted and a transmission area through which external light is transmitted, the method comprising:

45 forming a plurality of pixel circuit portions on a substrate to respectively correspond to the plurality of pixels; forming a first electrode that is disposed in a light emission area of each of the plurality of pixels and is electrically connected to a corresponding one of the pixel circuit portions; forming an intermediate layer, including an organic emissive layer, on the first electrode; forming a second electrode on the intermediate layer; and forming a capping layer on the second electrode, wherein the capping layer comprises a first capping layer corresponding to the light emission area and a second capping layer corresponding to the transmission area.

The first capping layer and the second capping layer may be formed separately.

50 The first capping layer and the second capping layer may be formed using a mask.

The capping layer may be formed in a first area on the second electrode and have a first edge, the method may further include forming a third electrode that is formed in a second area other than the first area on the second electrode and has a second edge, and a lateral surface of the first edge of the capping layer and a lateral surface of the second edge of the third electrode are formed to contact each other.

The forming of the third electrode may comprise patterning the third electrode by using a pattern of the capping layer.

BRIEF DESCRIPTION OF THE DRAWINGS

The above and other features and advantages of the present invention will become more apparent by describing in detail exemplary embodiments thereof with reference to the attached drawings in which:

FIG. 1 is a cross-sectional view illustrating an organic light-emitting display apparatus according to an embodiment of the present invention;

FIG. 2 is a cross-sectional view illustrating an organic light-emitting display apparatus according to another embodiment of the present invention;

FIG. 3 is a plan view illustrating an organic light-emitting unit of FIG. 1;

FIG. 4 is a cross-sectional view illustrating a pixel of FIG. 3;

FIG. 5 is a detailed plan view of a capping layer of the organic light-emitting unit of FIG. 1, according to an embodiment of the present invention;

FIG. 6 is a plan view of a capping layer of the organic light-emitting unit, according to another embodiment of the present invention;

FIG. 7 is a plan view of a capping layer of the organic light-emitting unit, according to another embodiment of the present invention;

FIG. 8 is a plan view illustrating an organic light-emitting unit according to another embodiment of the present invention; and

FIG. 9 is a graph showing light transmittance according to thickness of a capping layer.

DETAILED DESCRIPTION

The present invention will now be described more fully with reference to the accompanying drawings, in which exemplary embodiments of the invention are shown. As used herein, the term "and/or" includes any and all combinations of one or more of the associated listed items. Expressions such as "at least one of," when preceding a list of elements, modify the entire list of elements and do not modify the individual elements of the list.

FIG. 1 is a cross-sectional view illustrating an organic light-emitting display apparatus 2 according to an embodiment of the present invention.

Referring to FIG. 1, the organic light-emitting display apparatus 2 includes a substrate 1, an organic light-emitting unit 21 formed on the substrate 1, and an encapsulation substrate 23 that encapsulates the organic light-emitting unit 21.

The encapsulation substrate 23 includes a transparent material so that visible rays generated by the organic light-emitting unit 21 may transmit therethrough, and prevents (blocks) penetration of external air and water into the organic light-emitting unit 21.

The substrate 1 and the encapsulation substrate 23 are coupled using a sealing member 24 so that space 25 between the substrate 1 and the encapsulation substrate 23 is encapsulated. A moisture absorbing material or filler may be included in the space 25.

FIG. 2 is a cross-sectional view illustrating an organic light-emitting display apparatus 2 according to another embodiment of the present invention. Instead of the encapsulation substrate 23 of FIG. 1, a thin encapsulation layer 26

may be formed on an organic light-emitting unit 21, as illustrated in FIG. 2, to protect the organic light-emitting unit 21 from external air. The encapsulation layer 26 may have a structure in which an inorganic layer formed of silicon oxide or silicon nitride or the like and an organic layer formed of epoxy or polyimide or the like are alternately stacked, but is not limited thereto. Any encapsulation structure that is a thin transparent layer may be used.

FIG. 3 is a plan view illustrating the organic light-emitting unit 21 of FIG. 1, and FIG. 4 is a cross-sectional view illustrating a pixel of FIG. 3.

Referring to FIGS. 3 and 4, the organic light-emitting unit 21 is divided into a transmission area TA through which external light is transmitted and a plurality of light emission areas PA that are adjacent to the transmission area TA.

As illustrated in FIG. 3, in each of the light emission areas PA, a pixel circuit portion PC is included and a plurality of conductive lines, such as a scan line S, a data line D, and a Vdd line V, are electrically connected to the pixel circuit portion PC. Although not illustrated in FIG. 3, other conductive lines besides the scan line S, the data line D, and the Vdd line V may be included according to the configuration of the pixel circuit portion PC.

In FIG. 3, the pixel circuit portion PC may include at least one thin film transistor connected to the scan line S and the data line D, a thin film transistor connected to the Vdd line V, or the like, and a capacitor. The thin film transistors of the pixel circuit portion PC may include a switching transistor and a driving transistor. Also, the thin film transistors of the pixel circuit portion PC may be either p-type or n-type transistor, and the number of capacitors of the pixel circuit portion PC may vary.

Referring to FIG. 3, the scan line S overlaps with a first electrode 221. However, the embodiment of the present invention is not limited thereto, and at least one of the plurality of conductive lines, such as the scan line S, the data line D, and the Vdd line V, may be disposed to overlap with the first electrode 221, and also, according to circumstances, all of the plurality of conductive lines, such as the scan line S, the data line D, and the Vdd line V, may overlap with the first electrode 221 or may be disposed next to the first electrode 221.

Referring to FIG. 4, a buffer layer 211 is formed on a substrate 1, and a thin film transistor TR1 is formed on the buffer layer 211.

While only one thin film transistor TR1 is illustrated in FIG. 4, the embodiment of the present invention is not limited thereto, as described above, and a plurality of transistors and at least one capacitor may be included in each pixel.

A semiconductor active layer 212 is formed on the buffer layer 211.

The buffer layer 211 prevents penetration of impurities into the substrate 1 and provides a planar surface over the substrate 1. The buffer layer 211 may be formed of any materials that may perform these functions. For example, the buffer layer 211 may include an inorganic material, such as silicon oxide, silicon nitride, silicon oxynitride, aluminum oxide, aluminum nitride, titanium oxide, or titanium nitride, or an organic material such as polyimide, polyester, or acryl, and may also be formed of a stack structure of such materials. However, the buffer layer 211 is not an essential component and may be omitted when suitable.

The semiconductor active layer 212 may be formed of polycrystalline silicon, but is not limited thereto, and may be formed of an oxide semiconductor. For example, the semi-

conductor active layer **212** may be a G-I—Z—O layer [(In₂O₃)_a(Ga₂O₃)_b(ZnO)_c layer](where a, b, and c respectively satisfy a≥0, b≥0, c>0).

A gate insulating layer **213** is formed on the buffer layer **211** to cover the semiconductor active layer **212**, and a gate electrode **214** is formed on the gate insulating layer **213**.

An interlayer insulating layer **215** is formed to cover the gate electrode **214**. A source electrode **216** and a drain electrode **217** are formed on the interlayer insulating layer **215** to be electrically connected to the semiconductor active layer **212**.

The thin film transistor TR1 is not limited to the above-described structure, and other thin film transistor structures may be applied. For example, the thin film transistor TR1 described above has a top gate structure, but the thin film transistor TR1 may also have a bottom gate structure in which the gate electrode **214** is disposed below the semiconductor active layer **212**. Also, other thin film transistor structures may be used.

A passivation layer **218** is formed on the interlayer insulating layer **215** to cover the pixel circuit portion PC including the thin film transistor TR1. The passivation layer **218** may be a single insulating layer or a plurality of insulating layers having a planarized upper surface. The passivation layer **218** may be formed of an inorganic and/or organic material.

A first electrode **221** that is electrically connected to the thin film transistor TR1 is formed on the passivation layer **218**. The first electrode **221** is formed to be in an independent island form in each pixel.

A pixel-defining layer **219** is formed on the passivation layer **218** to cover an edge of the first electrode **221**. An opening **219a** is formed in the pixel-defining layer **219** to expose a central portion of the first electrode **221** except the edge thereof.

An intermediate layer **220**, including an organic emissive layer, is formed on the exposed central portion of the first electrode **221**, and a second electrode **222** is formed on the intermediate layer **220** to cover the intermediate layer **220**, thereby completing the manufacture of an organic light-emitting device EL.

The intermediate layer **220** may include a low-molecule or polymer organic layer. When the intermediate layer **220** is formed of a low-molecule organic layer, the intermediate layer **220** may include a hole injection layer (HIL), a hole transport layer (HTL), an organic emissive layer, an electron transport layer (ETL), an electron injection layer (EIL), or the like. The organic emissive layer is formed in each of red, green, and blue pixels, and the HIL, the HTL, the ETL, and the EIL are common layers that are commonly applied to the red, green, and blue pixels.

The HIL may be formed of a phthalocyanine compound such as a copper phthalocyanine or a starburst type amine such as TCTA, m-MTDATA, m-MTDAPB or the like.

The HTL may be formed of, for example, NN-bis(3-methylphenyl)-N,N'-diphenyl-[1,1-biphenyl]-4,4'-diamine (TPD), N,N'-di(naphthalene-1-yl)-N,N'-diphenyl benzidine (α -NPD), or the like.

The EIL may be formed of, for example, LiF, NaCl, CsF, Li₂O, BaO, or Liq.

The ETL may be formed using Alq₃.

The organic emissive layer may include a host material and a dopant material.

The host material of the organic emissive layer may be, for example, tris(8-hydroxy-quinolino)aluminum (Alq₃), 9,10-di(naphthi-2-yl)anthracene (AND), 3-Tert-butyl-9,10-di(naphthi-2-yl)anthracene (TBADN), 4,4'-bis(2,2-diphenyl-

ethene-1-yl)-4,4'-dimethylphenyl (DPVBi), 4,4'-bisBis(2,2-diphenyl-ethene-1-yl)-4,4'-dimethylphenyl (p-DMDPVBi), Tert(9,9-diarylfuorene)s (TDAF), 2-(9,9'-spirobifluorene-2-yl)-9,9'-spirobifluorene (BSDF), 2,7-bis(9,9'-spirobifluorene-2-yl)-9,9'-spirobifluorene (TSDF), bis(9,9-diarylfuorene)s (BDAF), 4,4'-bis(2,2-diphenyl-ethene-1-yl)-4,4'-di(tert-butyl)phenyl (p-TDPVBi), 1,3-bis(carbazole-9-yl)benzene (mCP), 1,3,5-tris(carbazole-9-yl)benzene (tCP), 4,4',4''-tris(carbazole-9-yl)triphenylamine (TcTa), 4,4'-bis(carbazole-9-yl)biphenyl (CBP), 4,4'-bisBis(9-carbazolyl)-2,2'-dimethyl-biphenyl (CBDP), 4,4'-bis(carbazole-9-yl)-9,9-dimethyl-fluorene (DMFL-CBP), 4,4'-bis(carbazole-9-yl)-9,9-bisbis(9-phenyl-9H-carbazole)fluorene (FL-4CBP), 4,4'-bis(carbazole-9-yl)-9,9-di-tolyl-fluorene (DPFL-CBP), or 9,9-bis(9-phenyl-9H-carbazole)fluorene (FL-2CBP).

The dopant material of the organic emissive layer may be, for example, 4,4'-bis[4-(di-p-tolylamino)styryl]biphenyl (DPAVBi), 9,10-di(naph-2-tyl)anthracene (ADN), or 3-tert-butyl-9,10-di(naph-2-tyl)anthracene (TBADN).

The first electrode **221** may function as an anode, and the second electrode **222** may function as a cathode, but the polarities of the first and second electrodes **221** and **222** may be exchanged.

When the first electrode **221** functions as an anode, the first electrode **221** may include a material having a high work function, such as ITO, IZO, ZnO, or In₂O₃. Also, according to purpose or design, the first electrode **221** may further include a reflection layer formed of, for example, Ag, Mg, Al, Pt, Pd, Au, Ni, Nd, Ir, Cr, Li, Yb, or Ca.

When the second electrode **222** functions as a cathode electrode, the second electrode **222** may be formed of a metal, such as Ag, Mg, Al, Pt, Pd, Au, Ni, Nd, Ir, Cr, Li, or Ca. When the organic light-emitting display apparatus **2** is a top emissive type display apparatus in which an image is formed away from the substrate **1**, light needs to be transmitted through the second electrode **222**. To this end, the second electrode **222** may include a transparent metal oxide, such as ITO, IZO, ZnO, or In₂O₃. Alternatively, the second electrode **222** may be formed as a thin film by using Al, Ag, and/or Mg. For example, the second electrode **222** may be formed in a single-layer structure or a stack structure including Mg:Ag and/or Ag. Unlike the first electrode **221**, the second electrode **222** is formed such that a common voltage is applied to each of all pixels thereof, and to this end, the second electrode **222** is formed as a common electrode to all pixels and is not formed of a plurality of patterns to correspond to pixels. Alternatively, the second electrode **222**, which is the common electrode, may also be patterned into a mesh form, from which portions except those corresponding to a light emission area are removed.

When the second electrode **222** is formed as a common electrode, surface resistance of the second electrode **222** is increased, thereby causing voltage drop (IR drop). According to the current embodiment of the present invention, to solve this issue, a third electrode **223** that is electrically connected to the second electrode **222** may be further included.

In addition, an upper surface of the second electrode **222** may be damaged by the encapsulation substrate **23** of FIG. 1. Moreover, when forming the encapsulation layer **26** as illustrated in FIG. 2, the second electrode **222** is likely to be damaged when forming the encapsulation layer **26**. Also, the second electrode **222** is likely to be damaged by external air or impurities. According to the current embodiment of the present invention, a capping layer **230** may be formed on the second electrode **222**.

The capping layer 230 includes a first capping layer 231 and a second capping layer 232. The first capping layer 231 may be formed to correspond to the light emission area PA, and the second capping layer 232 may be formed to correspond to the transmission area TA. Also, the first capping layer 231 and the second capping layer 232 may be formed separately. In more detail, the thicknesses of the first capping layer 231 and the second capping layer 232 may be different, and in particular, a thickness of the second capping layer 232 may be less than that of the first capping layer 231.

The capping layer 230 is formed on the second electrode 222 in a first area R1 and has a first edge 230a.

The third electrode 223 is formed on the second electrode 222 in a second area R2 and has a second edge 223a. The third electrode 223 is adjacent and horizontal to the capping layer 230.

The first area R1 corresponds to the light emission area PA and the transmission area TA in at least one pixel, and an edge of the first area R1 is the first edge 230a of the capping layer 230. The second area R2 corresponds to a portion of the second electrode 222 other than (or except) the first area R1, the third electrode 223 is formed over the entire second area R2, and an edge of the second area R2 is the second edge 223a of the third electrode 223. The second area R2 is an area except at least the light emission area PA.

A lateral surface of the first edge 230a of the capping layer 230 and a lateral surface of the second edge 223a of the third electrode 223 contact each other.

The third electrode 223 may preferably be thicker than the second electrode 222 to reduce surface resistance of the second electrode 222.

The capping layer 230 may preferably be light-transmissive. In particular, in the transmission area TA, desirably, visible rays transmit through the second capping layer 232 as much as possible without losing optical characteristics, and thus, transmittance of the second capping layer 232 may preferably be high.

Also, in the light emission area PA, desirably, visible rays generated by the intermediate layer 220 should transmit through the first capping layer 231 without losing optical characteristics. That is, the first capping layer 231 may preferably be formed such that visible rays generated by the intermediate layer 220 transmit through the first capping layer 231 and image quality, such as luminance, contrast, color conversion, or the like, are considered at the same time.

For example, the second capping layer 232 may be thinner than the first capping layer 231 to improve transparency of the transmission area TA and image quality of the light emission area PA.

The capping layer 230 may be formed as a thin layer that is thinner than the third electrode 223, but is not limited thereto.

According to an embodiment of the present invention, an adhesive force between the third electrode 223 and the capping layer 230 is set to be weaker than an adhesive force between the third electrode 223 and the second electrode 222.

To this end, the capping layer 230 may be formed of a material including 8-quinolinolato lithium (Liq), N,N-diphenyl-N,N-bis(9-phenyl-9H-carbazol-3-yl)biphenyl-4,4'-diamine, N(diphenyl-4-yl)9,9-dimethyl-N-(4(9-phenyl-9H-carbazol-3-yl)phenyl)-9H-fluorene-2-amine, or 2-(4-(9,10-di(naphthalene-2-yl)anthracene-2-yl)phenyl)-1-phenyl-1H-benzo-[D]imidazole.

The first capping layer 231 and the second capping layer 232 may be formed using the same material for simplicity of

manufacture, but the embodiment of the present invention is not limited thereto, and the first capping layer 231 and the second capping layer 232 may also include different materials.

Also, the third electrode 223 may be formed of magnesium (Mg).

Magnesium (Mg) of the third electrode 223 is a metal, and thus, has a good adhesive property with respect to the second electrode 222. However, Mg is not easily adhered to the material of the capping layer 230. Thus, the third electrode 223 may be easily patterned by using the adhesive force between the third electrode 223 and the capping layer 230.

As described above, the third electrode 223 is patterned so that the third electrode 223 is formed only in the second area R2. However, after forming the intermediate layer 220 of the organic light-emitting device EL, the third electrode 223 may not be patterned using a wet process such as a photolithography method which is frequently used as a patterning method of a typical metal layer, because when water and/or oxygen penetrates into the intermediate layer 220 in the wet process, the lifespan (lifetime) of the organic light-emitting device EL is abruptly decreased.

Thus, it is difficult to pattern the third electrode 223 in actuality.

According to the current embodiment of the present invention, the third electrode 223 may be simply patterned using an adhesive force between the third electrode 223 and the capping layer 230. Hereinafter, a method of manufacturing the capping layer 230, according to an embodiment of the present invention, will be described in more detail.

First, the manufacturing method is the same until forming the second electrode 222, and then a mask is used to form the capping layer 230. The capping layer 230 may be formed of an organic material described above, and thus, may be formed using a thermal evaporation method using a mask. An opening is formed in the mask to correspond to a pattern of the capping layer 230.

Here, the first capping layer 231 and the second capping layer 232 are formed separately. That is, the first capping layer 231 is formed using a mask having an opening corresponding to the first capping layer 231, and then the second capping layer 232 is formed using a mask having an opening corresponding to the second capping layer 232. Referring to FIG. 5, the first capping layer 231 and the second capping layer 232 have different sizes, and in this case, the first capping layer 231 and the second capping layer 232 may be formed using different masks.

However, the embodiment of the present invention is not limited thereto, and when the first capping layer 231 and the second capping layer 232 are to be formed similarly, the first capping layer 231 may be formed first using a mask, and then the mask may be used to form the second capping layer 232.

Alternatively, the first capping layer 231 may be formed after forming the second capping layer 232.

Then, an open mask having an overall opening corresponding to all pixels is used to form the third electrode 223 using a material for forming the third electrode 223. In this case, the material for forming the third electrode 223 has poor adhesive force with respect to the capping layer 230, and thus, is not formed on the capping layer 230, and is formed only on the second electrode 222, which has a relatively good adhesive force.

Accordingly, the third electrode 223 may be spontaneously (naturally) patterned at a desired position without an additional patterning operation such as a photolithography method.

FIG. 5 is a detailed plan view of the capping layer 230 of the organic light-emitting unit 21 of FIG. 1, according to an embodiment of the present invention. As illustrated in FIG. 5, the capping layer 230 may be formed to be in an island form in each pixel P. The first capping layer 231 and the second capping layer 232 are formed separately, and thus, may be spaced apart from each other. However, the embodiment of the present invention is not limited thereto, and the first capping layer 231 and the second capping layer 232 may be formed adjacent to each other or may overlap by a portion, particularly, edge portions thereof.

The third electrode 223 is arranged as a lattice pattern between pixels P.

FIG. 6 is a plan view of a capping layer 230 of the organic light-emitting unit 21 according to another embodiment of the present invention. In FIG. 6, as an example of the capping layer 230 of the organic light-emitting unit 21 of FIG. 1, the second capping layer 232 of the capping layer 230 may include sub-capping layers 232A and 232B. In this case, when forming the capping layer 230, the first capping layer 231, the sub-capping layer 232A, and the sub-capping layer 232B may be sequentially formed. That is, the capping layer 230 may be formed by three operations. The capping layer 230 may also be formed using a single mask. A boundary between the sub-capping layer 232A and the second sub-capping layer 232B may be in the transmission area.

Also, the sub-capping layers 232A and 232B of the second capping layer 232 include the above-described materials for forming the capping layer 230 and may be formed of the same material. However, the embodiment of the present invention is not limited thereto, and the sub-capping layers 232A and 232B of the second capping layer 232 may also be formed using different materials.

Also, according to another embodiment of the present invention, the capping layer 230 of the organic light-emitting unit 21 of FIG. 1 may be formed to be in an island form in a plurality of pixels P as illustrated in FIG. 7. In this case, the third electrode 223 is arranged as a lattice pattern that passes by spaces between the plurality of pixels P. Although not illustrated in FIG. 7, the second capping layer 232 of the capping layer 230 may also include a plurality of sub-capping layers, as illustrated in FIG. 6.

Although not illustrated in the drawings, when forming the third electrode 223, a material for forming the third electrode 223 may be formed not only in an area except the capping layer 230, but also as a thin layer that is thinner than the third electrode 223 formed in the area except the capping layer 230, since the material for forming the third electrode 223 has poor adhesive force with respect to the capping layer 230. That is, the material should theoretically not form as a layer on the capping layer 230. In addition, even if the material is formed as a layer only on the second electrode 222 having a relatively good adhesive force, the material for forming the third electrode 223 is deposited without using an additional patterning mask but using an open mask. Consequently, a very thin layer may be formed on the capping layer 230 in a physically unstable state.

However, since the material for forming the third electrode 223, which may be formed on the capping layer 230, is very thin, the material does not have a great influence on the luminance of the organic light-emitting device EL.

According to the current embodiment of the present invention, as the light emission area PA and the transmission area TA are separate, when observing the outside through the transmission area TA, distortion of external images gener-

ated due to diffusion of external light related to patterns of devices in the pixel circuit portion PC may be reduced or prevented.

The light emission area PA and the transmission area TA are formed such that a ratio of a surface area of the transmission area TA with respect to the total surface area of the light emission area PA and the transmission area TA is in a range from about 5% to about 90%.

In one embodiment, if the ratio of the surface area of the transmission area TA with respect to the total surface area of the light emission area PA and the transmission area TA is less than 5%, the amount of light that is transmitted through the transmission area TA may be small, and thus, a viewer may have difficulty viewing an object or an image on the opposite side of the organic light-emitting display apparatus 2. That is, the organic light-emitting unit 21 may not be regarded as transparent. However, even if the ratio of the surface area of the transmission area TA with respect to the total surface area of the light emission area PA and the transmission area TA is about 5%, if an intensity of external light is high, a user may sufficiently recognize an object or an image disposed on the opposite side, through the organic light-emitting display apparatus 2, and thus, the user may regard the organic light-emitting unit 21 as a transparent display unit. In addition, when the thin film transistor of the pixel circuit portion PC is formed as a transparent thin film transistor, such as an oxide semiconductor, and an organic light-emitting device is also formed of a transparent device, the effect of the organic light-emitting display apparatus 2 as a transparent display apparatus may be enhanced.

In another embodiment, if the ratio of the surface area of the transmission area TA with respect to the total surface area of the light emission area PA and the transmission area TA is greater than 90%, pixel integration of the organic light-emitting unit 21 is too low and images may not be stably formed through light emission of the light emission area PA. That is, the smaller the surface area of the light emission area PA, the higher the need of luminance of light emitted from the intermediate layer 220. Thus, if an organic light-emitting device is operated in a high luminance mode, the lifespan (lifetime) of the organic light-emitting display apparatus 2 is abruptly decreased.

Thus, the ratio of the surface area of the transmission area TA with respect to the total surface area of the light emission area PA and the transmission area TA may preferably be in a range from 20% to 70%.

In one embodiment, if the ratio is less than 20%, the surface area of the light emission area PA is exceedingly greater than that of the transmission area TA, and a user has difficulty viewing images outside through the transmission area TA. In another embodiment, if the ratio exceeds 70%, designing the pixel circuit portion PC, which is to be arranged in the light emission area PA, may be restricted too much.

The first electrode 221 that is electrically connected to the pixel circuit portion PC is included in the light emission area PA, and the pixel circuit portion PC overlaps with the first electrode 221 so as to be covered by the first electrode 221. In addition, at least one of the conductive lines, including the scan line S, the data line D, and the Vdd line V, described above may be arranged to cross the first electrode 221. However, since a ratio at which these conductive lines hinder transmittance is less than that of the pixel circuit portion PC, all of the conductive lines may be disposed adjacent to the first electrode 221 according to design conditions.

As described above, if the first electrode **221** includes a reflection layer formed of a conductive metal on which light may be reflected, the first electrode **221** covers the pixel circuit portion PC and reduces or prevents distortion of external images in the light emission area PA due to the pixel circuit portion PC.

Also, according to the current embodiment of the present invention, as illustrated in FIGS. **3** and **4**, the light emission area PA and the transmission area TA are arranged in the first area R1. The capping layer **230** is disposed within the first area R1, and thus, covers both the light emission area PA and the transmission area TA. In addition, the third electrode **223** is formed in the second area R2 outside the first area R1.

In addition, a transmission window may be formed by removing a portion of the second electrode **222** from the transmission area TA, thereby further increasing light transmittance of the transmission area TA. Here, the transmission window is not limited to being formed by removing a portion of the second electrode **222** and may also be formed on at least one of the pixel-defining layer **219**, the passivation layer **218**, the interlayer insulating layer **215**, the gate insulating layer **213**, and the buffer layer **211**.

FIG. **8** is a plan view illustrating an organic light-emitting unit according to another embodiment of the present invention.

Referring to FIG. **8**, each pixel is formed of red, green, and blue sub-pixels so as to emit white light. However, white light may also be generated by using colors other than red, green, and blue colors.

In this case, one transmission area TA for each of first electrodes **221a**, **221b**, and **221c** of the three sub-pixels is formed. First through third data lines D1 through D3 are electrically connected to the first electrodes **221a**, **221b**, and **221c** of the three sub-pixels. Also, a first Vdd line V1 is electrically connected to the first electrodes **221a** and **221b**, and a second Vdd line V2 is electrically connected to the first electrode **221c**.

In this structure, one large transmission area TA is included for a plurality of sub-pixels, and thus, transmittance of the entire display apparatus may be further increased and distortion of images due to light diffusion may also be further reduced.

Here, one large transmission window may also be formed by removing at least a portion of a second electrode from the transmission area TA, as described above. The transmission window is not limited to the removed portion of the second electrode but may also be formed on at least one of a pixel-defining layer, a passivation layer, an interlayer insulating layer, a gate insulating layer, and a buffer layer.

A capping layer and a third electrode are also formed in the embodiment of FIG. **8** described above. That is, a capping layer is formed to correspond to a transmission area and a light emission area, and the third electrode is formed around the capping layer. Also, a first capping layer is formed in the light emission area, and a second capping layer is formed in the transmission area. The light emission area of FIG. **8** may be regarded as corresponding to areas of the first electrodes **221a**, **221b**, and **221c**. The other detailed configuration is the same as the previous embodiment(s), and thus, description thereof is omitted.

FIG. **9** is a graph showing light transmittance according to thickness of a capping layer. Referring to FIG. **9**, an area A has a large transmittance, and an area B has a lower light transmittance than the area A.

As described above, the first capping layer **231** and the second capping layer **232** of the capping layer **230** are separately formed.

Visible rays transmit through the transmission area TA, and transmittance of the second capping layer **232** may preferably be high. However, the second electrode **222** below the second capping layer **232** may preferably be formed such that a thickness of the second capping layer **232** is sufficient to protect the second electrode **222**. In more detail, the second capping layer **232** may have a thickness corresponding to the area A, that is, a range from about 30 Å to about 60 Å.

In the light emission area PA, an image is formed through visible rays generated by the intermediate layer **220**, and thus, a suitable thickness of the first capping layer **231** is determined in consideration of luminance, contrast, and color conversion of visible rays. In more detail, the first capping layer **231** may have a thickness corresponding to the area B, that is, a range from about 70 Å to about 90 Å.

As a result, the first capping layer **231** is thicker than the second capping layer **232**.

However, this is an example, and alternatively, the first capping layer **231** and the second capping layer **232** may be each formed to have suitable thicknesses. In more detail, considering optical characteristics, the organic light-emitting display apparatus **2** may suitably vary according to the material of the intermediate layer **220**, and a suitable thickness of the first capping layer **231** may vary accordingly. Also, different materials may be determined to form the first capping layer **231** and the second capping layer **232**, and a range of suitable thicknesses thereof may also vary.

As described above, a voltage drop of the second electrode **222** is reduced or prevented by using the third electrode **223** to improve electrical characteristics of the organic light-emitting display apparatus **2**, thereby improving image quality of the organic light-emitting display apparatus **2**.

Also, the second electrode **222** is protected by using the capping layer **230** to, e.g., completely prevent deterioration of electrical characteristics and image quality of the organic light-emitting display apparatus **2** due to damage of the second electrode **222**.

In particular, the third electrode **223** is easily patterned using the capping layer **230** to increase manufacturing simplicity and prevent damage of the organic light-emitting device EL when forming the third electrode **223**.

Also, the capping layer **230** includes the first capping layer **231** and the second capping layer **232**, and the first capping layer **231** is formed to correspond to the light emission area PA, and the second capping layer **232** is formed to correspond to the transmission area TA. Accordingly, as many visible rays as possible transmit through the transmission area TA, and suitable images are formed in the light emission area PA. The organic light-emitting display apparatus **2** suitable for use as a transparent display apparatus having excellent image quality and transmittance may be easily manufactured.

According to the organic light-emitting display apparatus and the method of manufacturing the same, electrical characteristics and image quality of the organic light-emitting display apparatus may be easily improved.

While the present invention has been particularly shown and described with reference to exemplary embodiments thereof, it will be understood by those of ordinary skill in the art that various changes in form and details may be made therein without departing from the spirit and scope of the present invention as defined by the following claims.

What is claimed is:

1. A method of manufacturing an organic light-emitting display apparatus comprising a plurality of pixels each comprising a light emission area from which visible rays are

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emitted and a transmission area through which external light is transmitted, the method comprising:

forming a plurality of pixel circuit portions on a surface of a substrate to respectively correspond to the plurality of pixels;

forming a first electrode in a light emission area of each of the plurality of pixels and electrically connected to a corresponding one of the pixel circuit portions;

forming an intermediate layer, comprising an organic emissive layer, on the first electrode;

forming a second electrode on the intermediate layer;

forming a first capping layer on the second electrode corresponding to the light emission area; and

forming a second capping layer separate from the first capping layer, the second capping layer being formed on the second electrode, spaced from at least a region of the first capping layer in a direction parallel to the surface of the substrate, and corresponding to the transmission area,

wherein the second capping layer comprises a plurality of sub-capping layers, the plurality of sub-capping layers comprising a first sub-capping layer and a second sub-capping layer arranged adjacent to each other in the direction parallel to the surface of the substrate, and

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wherein a boundary between the first sub-capping layer and the second sub-capping layer is in the transmission area.

2. The method of claim 1, wherein the first capping layer and the second capping layer are formed using a mask.

3. The method of claim 1, wherein: the first capping layer is formed in a first area on the second electrode and has a first edge,

the method further comprises forming a third electrode in a second area other than the first area on the second electrode and having a second edge, and a lateral surface of the first edge of the first capping layer and a lateral surface of the second edge of the third electrode are formed to contact each other.

4. The method of claim 3, wherein the forming of the third electrode comprises patterning the third electrode by using a pattern of the first and second capping layers.

5. The method of claim 1, wherein the first and second sub-capping layers are spaced from each other.

6. The method of claim 1, wherein the first capping layer and the second capping layer have different thicknesses from each other.

7. The method of claim 6, wherein the second capping layer is thinner than the first capping layer.

* * * * *

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摘要(译)

一种有机发光显示装置，包括：基板；多个像素形成在基板上，每个像素具有发射可见光的发光区域和透射外部光的透射区域；像素电路部分设置在多个像素的每个发光区域中；第一电极，设置在每个发光区域中并电连接到像素电路部分；中间层，形成在第一电极上并包括有机发光层；形成在中间层上的第二电极；盖层设置在第二电极上，并包括对应于发光区域的第一盖层和对应于透射区域的第二盖层。因此，可以改善有机发光显示装置的电特性和图像质量。

